

#### QUADRATURE DEMODUL

### Typical Applications

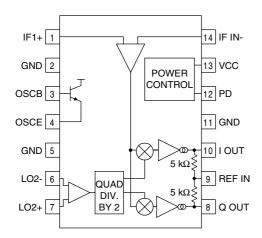
- UHF Digital and Analog Receivers
- Digital Communication Systems
- Spread Spectrum Communication Systems
  General Purpose Frequency Conversion
- Commercial and Consumer Systems
- Portable Battery Powered Equipment

#### **Product Description**

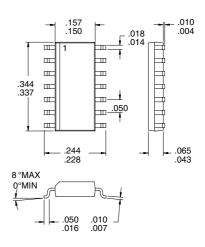
The RF2711 is a monolithic integrated quadrature demodulator intended for use in digital mobile radio receivers. In this application it is used to recover the Inphase and Quadrature baseband signals from the amplified and filtered IF. The RF2711 is intended for IF systems where the IF frequency ranges from 100kHz to 250MHz, and the LO frequency is two times the IF. The IC contains all of the required components to implement the demodulation function of the receiver and contains a digital divider type 90° phase shifter, two double balanced mixers, and baseband amplifiers designed to interface with Analog to Digital Converters. The output DC offset may be slaved to the reference of the ADCs to maintain DC accuracy.

#### **Optimum Technology Matching® Applied**

Si BJT GaAs HBT GaAs MESFET Si Bi-CMOS SiGe HBT Si CMOS



**Functional Block Diagram** 



Package Style: SOP-14

#### **Features**

- 5V Power Supply
- On-Chip Active Device for Oscillator
- ADC Compatible Outputs
- Low LO Power Requirement
- Digitally Controlled Power Down Mode
- 100kHz to 250MHz IF Operation

#### Ordering Information

RF2711 Quadrature Demodulator RF2711 PCBA Fully Assembled Evaluation Board

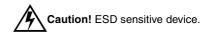
RF Micro Devices. Inc. 7625 Thorndike Road Greensboro, NC 27409, USA

Tel (336) 664 1233 Fax (336) 664 0454 http://www.rfmd.com

# RF2711

#### **Absolute Maximum Ratings**

Parameter	Rating	Unit
Supply Voltage	-0.5 to +7.0	$V_{DC}$
Power Down Voltage (V <sub>PD</sub> )	-0.5 to V <sub>CC</sub>	$V_{DC}$
IF Input Level	2.0	$V_{PP}$
LO Input Power	+10	dBm
Operating Ambient Temperature	-40 to +85	°C
Storage Temperature	-40 to +150	°C



RF Micro Devices believes the furnished information is correct and accurate at the time of this printing. However, RF Micro Devices reserves the right to make changes to its products without notice. RF Micro Devices does not assume responsibility for the use of the described product(s).

Parameter	Specification		Unit	Condition	
Parameter	Min. Typ. Max.		Offic	Condition	
Overall					T=25°C, V <sub>CC</sub> =5.0V
IF Frequency Range		0.1 to 250		MHz	
Baseband Frequency Range		DC to >10		MHz	Load Impedance > $5k\Omega$ , $C_{SHUNT}$ < 1pF
Baseband Frequency Range		DC to 1		MHz	Load Impedance > $5k\Omega$ , $C_{SHUNT}$ < $10pF$
Input Impedance		1000-j1300		Ω	At 50MHz, each input
Output Impedance		5000		Ω	•
Maximum Output		>1.25		$V_{PP}$	With 250mV input
Gain	13	14		dB	Small-signal, 100mV input
I/Q Amplitude Balance		0.1	0.5	dB	
I/Q Phase Accuracy		±1	±5	0	
Reference Voltage		1.5 to 3.5		V	The reference voltage input should provide a low impedance at the I/Q frequency. The voltage sets the DC level seen on the I and Q ports.
DC Offset		3	20	mV	I to Q
DC Offset		3	20	mV	I or Q to REF IN
LO					
Oscillator					Use provided transistor or external LO
Frequency					Twice (2x) the IF frequency
Level		0.1-1		$V_{PP}$	
Input Impedance		400-j1200		Ω	At 100MHz
Power Down					
Turn On/Off Time		<100		ns	
PD Input Resistance		>50		kΩ	
Power Down "ON"		2.5	3.0	V	Threshold voltage; Part is "ON"
Power Down "OFF"	0.5	0.8		V	Threshold voltage; Part is "OFF"
Power Supply					
Voltage		5		V	Specifications
		4.5 to 5.5		V	Operating limits
Current		4.5	7.2	mA	Operating
		300	500	μΑ	Power Down

7-12 Rev B1 960209

		I=	
Pin	Function	Description	Interface Schematic
1	IF IN+	Balanced IF input. An input level of 400 mV <sub>PP</sub> gives full output swing; a level of maximum 250 mV <sub>PP</sub> is recommended for linear operation. This pin has no internal DC block, and an external capacitor of 100 nF is needed if connected to a DC path.	$\begin{array}{c c} \text{IF IN+} & \text{IF IN-} \\ 1500 \ \Omega \\ \hline \\ \text{BIAS} & \\ \end{array}$
2	GND	Ground connection. Keep traces physically short and connect immediately to ground plane for best performance.	
3	OSCB	Base of the LO transistor. This pin is not connected to anything else. This transistor can be used for an oscillator. The collector of the transistor is connected to $V_{CC}$ .	OSCB OSCE
4	OSCE	Emitter of the LO transistor. This pin is not connected to anything else. Maximum collector current of this device is 1 mA, $f_T$ =4.5 GHz, $h_{fe}$ =100	See pin 3.
5	GND	Same as pin 2.	
6	LO2-	Balanced input for the doubled LO. An internal divide-by-2 network generates the actual LO for the mixers. The divided signal is not accessible. When the LO is driven single ended this pin should be connected to a 100 nF capacitor to ground. This pin has an internal pull-up resistor to V <sub>CC</sub> and an external DC blocking capacitor of 100 nF is recommended.	LO2+ 200 Ω LO2- 200 Ω LO2
7	LO2+	Balanced input for the doubled LO. The input frequency should be twice (2x) the IF frequency. An internal divide-by-2 network generates the actual LO for the mixers. This pin has an internal pull-up resistor to V <sub>CC</sub> , and an external DC blocking capacitor of 100nF is recommended. LO frequencies below 100kHz are acceptable, providing that the LO signal is square wave. Above 100kHz a sine wave signal is acceptable. The quadrature accuracy of the LO/2 frequency into the mixers is affected by the duty cycle of the LO input signal. Square wave signals with other than 50% duty cycle will degrade the quadrature accuracy of the LO signal, thereby adversely affecting the I and Q quadrature accuracy. Since the LO input is AC coupled, asymmetric sine waves and sine waves clipped on either the top or bottom half will not have 50% duty cycles relative to the internal DC reference point. For this reason, distorted LO sine wave signals will degrade performance in a fashion similar to non-50% duty cycle square waves. A sine wave input with even harmonics less than -15dBc is recommended. The internal limiting buffer amplifier ensures the amplitude stability of the demodulator.	See pin 6.
8	Q OUT	Demodulated baseband Q output. The reference DC level of this pin is set by the voltage of pin 9 (REF IN), which is connected to this pin through a $5k\Omega$ resistor to the collectors of this push-pull output. This results in an output impedance of $5k\Omega$ if the REF IN pin is connected to a low impedance source. The capacitance of the load determines the maximum baseband frequency. A very low capacitive load may stretch the 3dB bandwidth over 10MHz. Another way to increase bandwidth is by connecting a shunt resistor. This will trade-off gain for bandwidth.	5 kΩ REF IN I/Q OUT
9	REF IN	Reference voltage input for the baseband outputs. This pin can be connected to the reference voltage source of the Analog to Digital Converter. It is connected to the I and Q outputs through $5k\Omega$ resistors. This pin should have an external decoupling capacitor large enough to decouple the lowest baseband frequency.	See pin 8.

Rev B1 960209 7-13

# RF2711

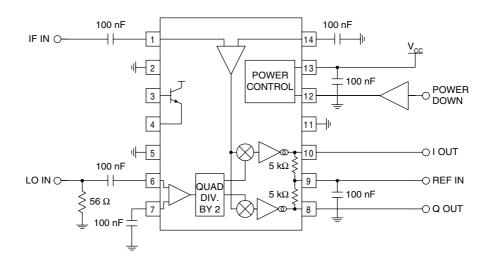
Pin	Function	Description	Interface Schematic
10	I OUT	Demodulated baseband I output. The reference DC level of this pin is set by the voltage of pin 9 (REF IN), which is connected to this pin through a $5k\Omega$ resistor to the collectors of this push-pull output. This results in an output impedance of $5k\Omega$ if the REF IN pin is connected to a low impedance source. The capacitance of the load determines the maximum baseband frequency. A very low capacitive load may stretch the 3dB bandwidth over 10MHz. Another way to increase bandwidth is by connecting a shunt resistor. This will trade gain for bandwidth.	See pin 8.
11	GND	Same as pin 2.	
12	PD	Power Down control. When this pin is "low", all circuits are shut off. A "low" is typically 0.8V or less at room temperature. When this pin is "high", all circuits are operating normally.	VCC PD
13	VCC	Power supply pin. An external 100nF bypass capacitor is recommended if no other bypass capacitor is nearby.	
14	IF IN-	Balanced IF input. An input level of 400 mV <sub>PP</sub> gives full output swing; a level of maximum 250 mV <sub>PP</sub> is recommended for linear operation. This pin has no internal DC block and an external capacitor of 100nF is needed if connected to a DC path. If the IF is driven by a single-ended source, connect this pin to an 100nF capacitor to ground.	See pin 1.

## Spice model for oscillator transistor:

.MODEL RFM2 npn (BF=115.5 VAF=40 IS=.00722F RE=12.1 RC=77.20 RB=1082.6 RBM=295.0 BR=0.6593 CJE=36.7F TF=24.485p CJC=38.75F CJS=161.1F)

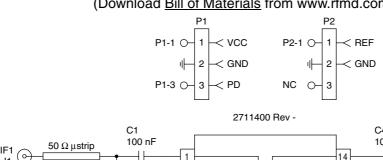
7-14 Rev B1 960209

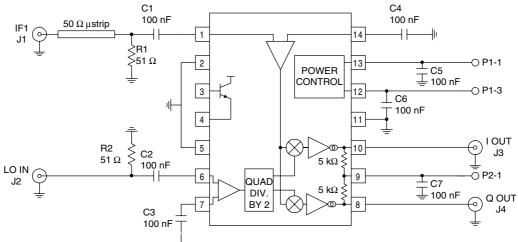
# **Application Schematic**



## **Evaluation Board Schematic**

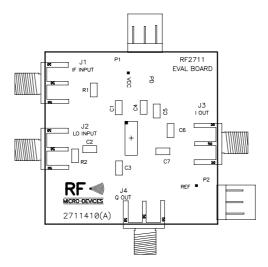
(Download Bill of Materials from www.rfmd.com.)

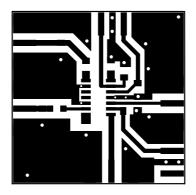




Rev B1 960209 7-15

# Evaluation Board Layout 1.5" x 1.5"





7-16 Rev B1 960209